



Bipolar PNP Bare Die – BTP036

Part Description

The BTP036 is a silicon BJT transistor available in bare die form and well suited for use in High Voltage Driver applications..

Key Parameters:

- VCBO = -600V
- VCEO = -600V
- VEBO = -7V
- hFE = 30-120 @ VCE = -5V, IC = -0.1A
- VCE(Sat) = -1V @ IC = -0.3A, IB = -60mA
- fT = 25 MHz @ VCE = -10V, IE = 0A
- COBO = 40pF @ VCB = -10V

Features

Designed to provide performance equivalent to RENESAS 2SA1413

Die Size (Unawn)

1940 μ m X 1940 μ m, 76 Mils X 76 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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